LD59030

Datasheet

300 mA very low dropout linear regulator IC

DFN4 1x1

Maturity status link
LD59030

Features

- Input voltage from 1.5 to 5.5 V
- Ultra low dropout voltage (135 mV typ. at 300 mA load)
- Very low quiescent current (28 µA typ. at no load, 0.03 µA typ. in off mode)
- Internal current fold-back
- Output voltage tolerance: ± 1 % @ 25 °C
- 300 mA guaranteed output current
- High PSRR: 75 dB@1 kHz
- Wide range of output voltages available on request: from 0.8 V up to 5.0 V in 50 mV step
- Logic-controlled electronic shutdown
- Internal soft-start
- Optional output voltage discharge feature
- Compatible with ceramic capacitor C_{OUT} = 0.47 µF
- Thermal protection
- Available in DFN4 1x1
- Operating temperature range: -40 °C to 125 °C

Description

The LD59030 high accuracy voltage regulator provides 300 mA of maximum current from an input voltage ranging from 1.5 V to 5.5 V, with a typical dropout voltage of 135 mV at V_{OUT} = 3.3 V.

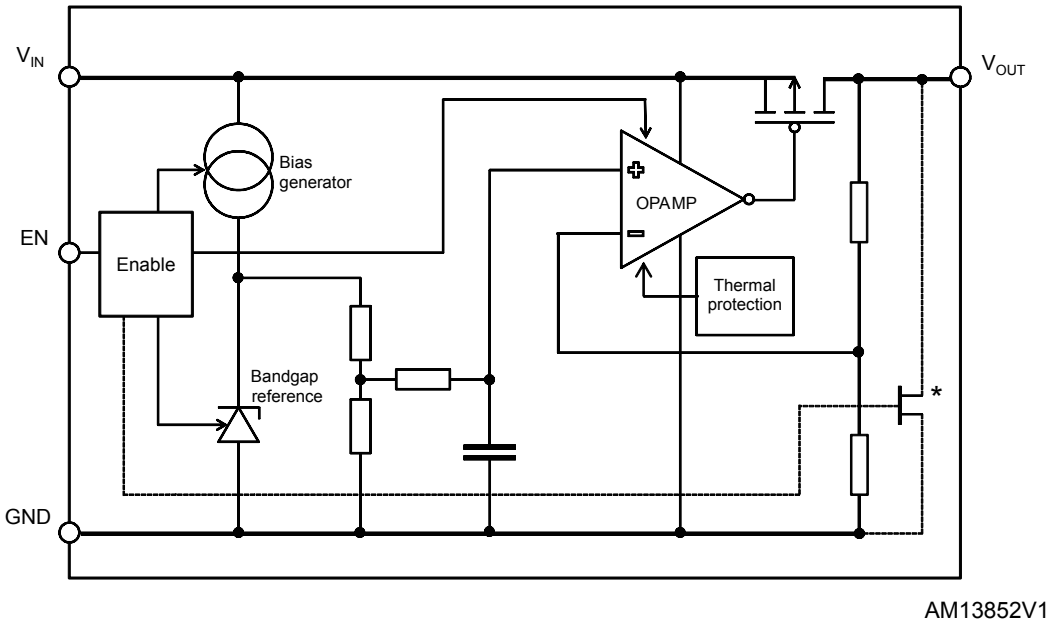
It is available in DFN4 1x1 package, allowing the maximum space saving.

The device works with a ceramic capacitor on the output. The ultra-low drop voltage, low quiescent current and low noise features, together with the internal soft-start circuit and output current fold-back protection, make the LD59030 suitable for low power battery-operated applications.

An enable logic control function puts the LD59030 in shutdown mode allowing a total current consumption lower than 0.03 µA.

1 Diagram

Figure 1. Block diagram

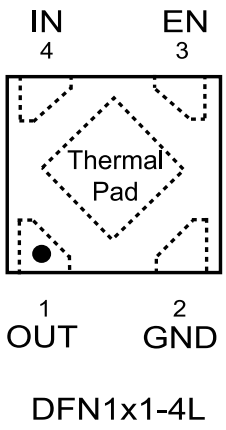


AM13852V1

Note: The output discharge MOSFET is optional.

2 Pin configuration

Figure 2. **Pin connection (top view)**



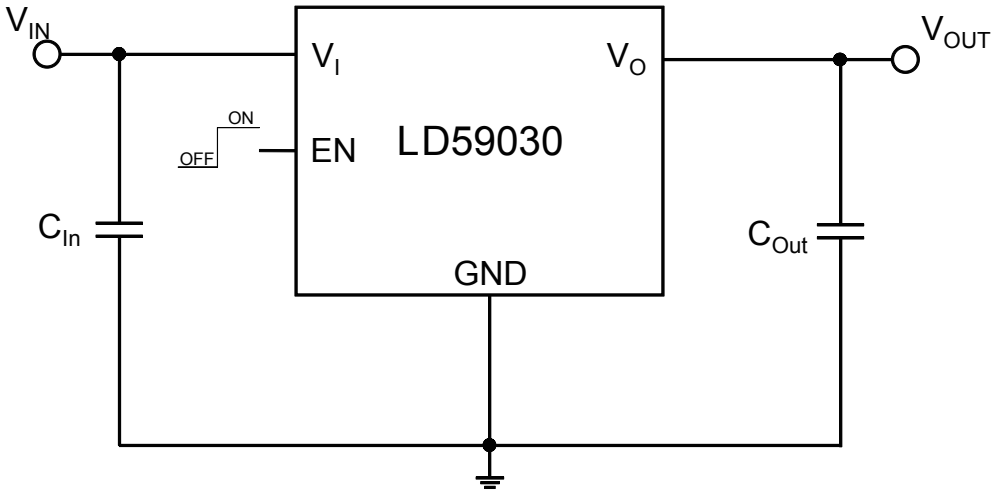
DFN1x1-4L

Table 1. **Pin description**

Pin n° DFN4 1x1	Symbol	Function
1	OUT	Output voltage
2	GND	Common ground
3	EN	Enable pin logic input: Low = shutdown, High = active
4	IN	Input voltage
Thermal pad	-	Connect to GND or floating

3 Typical application

Figure 3. **Typical application circuit**



4 Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{IN}	Input voltage	- 0.3 to 7	V
V_{OUT}	Output voltage	- 0.3 to V_{IN} + 0.3	V
V_{EN}	Enable input voltage	- 0.3 to 7	V
I_{OUT}	Output current	Internally limited	mA
P_D	Power dissipation	Internally limited	mW
T_{STG}	Storage temperature range	- 40 to 150	°C
T_{OP}	Operating junction temperature range	- 40 to 125	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All values are referred to GND.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJA}	Thermal resistance junction-ambient	140	°C/W

Table 4. ESD Performance

Symbol	Parameter	Test conditions	Value	Unit
ESD	ESD Protection voltage	HBM	2	kV
		CDM	500	V

5 Electrical characteristics

T_J = 25 °C, V_{IN} = $V_{OUT(NOM)}$ + 1 V , C_{IN} = C_{OUT} = 1 µF, I_{OUT} = 1 mA, V_{EN} = V_{IN}, unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IN}	Operating input voltage		1.5		5.5	V
V_{OUT}	V_{OUT} accuracy	I_{OUT} = 1 mA, T_J = 25 °C	-1		1	%
		I_{OUT} = 1 mA, -40 °C < T_J < 85 °C	-2		2	%
ΔV_{OUT}	Static line regulation (1)	$V_{OUT(NOM)}$ + 1 V ≤ V_{IN} ≤ 5.5 V, I_{OUT} = 10 mA		0.015		%/V
		-40 °C < T_J < 85 °C			0.05	
ΔV_{OUT}	Static load regulation	I_{OUT} = 0 mA to 300 mA		-20		mV
		I_{OUT} = 0 mA to 300 mA -40 °C < T_J < 85 °C		-0.004	-0.01	%/mA
V_{DROP}	Dropout voltage	I_{OUT} = 30 mA,V_{OUT} = 2.8 V		20		mV
		I_{OUT} = 300 mA, V_{OUT} = 2.8 V -40 °C < T_J < 85 °C		155	230	
e_N	Output noise voltage	10 Hz to 100 kHz, I_{OUT} = 10 mA, V_{OUT} = 1.8 V		70		μV_{RMS}
SVR	Supply voltage rejection	V_{IN} = $V_{OUT(NOM)}$+ 1 V +/- V_{RIPPLE} V_{RIPPLE} = 0.2 V Freq .=1 kHz I_{OUT} = 30 mA		75		dB
		V_{IN} = $V_{OUT(NOM)}$+ 1 V +/- V_{RIPPLE} V_{RIPPLE} = 0.2 V Freq. = 100 kHz I_{OUT} = 30 mA		55		
I_Q	Quiescent current	I_{OUT} = 0 mA		28	40	µA
		I_{OUT} = 300 mA		305		
$I_{Standby}$	Standby current	V_{IN} input current in OFF MODE: V_{EN} = GND		0.03	1	µA
I_{LIM}	Current limit	V_{OUT} = 0.9 x $V_{OUT(NOM)}$		500		mA
I_{SC}	Short circuit current	V_{OUT} = 0 (foldback protection)	120	170		mA
R_{ON}	Output voltage discharge MOSFET	(LD59030DT version) I_{OUT} = 1 mA		120		Ω
V_{EN}	Enable input logic low	V_{IN} = 1.5 V to 5.5 V -40 °C < T_J < 85 °C			0.4	V
	Enable input logic high	V_{IN} = 1.5 V to 5.5 V -40 °C < T_J < 85 °C	1			
I_{EN}	Enable pin input current	V_{EN} = V_{IN}			100	nA
T_{ON} (2)	Turn on time			145		µs
T_{SHDN}	Thermal shutdown			160		°C
	Hysteresis			20		

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{OUT}	Output capacitor	Capacitance (see Figure 15. Stability area vs. (C_{OUT}, ESR))	0.47		22	µF

1. *Not applicable for $V_{OUT(NOM)}$ > 4.5 V*
2. *Turn-on time is time measured between the enable input just exceeding VEN high value and the output voltage just reaching 95 % of its nominal value*

6 Application information

6.1 Soft-start function

The LD59030 has an internal soft start circuit. By increasing the startup time up to 145 µs, without the need of any external soft start capacitor, this feature is able to keep the regulator inrush current at startup under control.

6.2 Output discharge function

The LD59030 integrates a MOSFET connected between V_{OUT} and GND. This transistor is activated when the EN pin goes to low logic level and has the function to quickly discharge the output capacitor when the device is disabled by the user.

The device is available with or without auto-discharge feature.

See Section 9 Ordering information for more details.

6.3 Dropout voltage

Table 6. Dropout voltage at I_{OUT} = 300 mA

Output voltage [V]	Typical value [mV] T_J = 25°C	Max value [mV] -40 °C < T_J < 85 °C
1.05	400	550
1.2	330	490
1.5	260	390
1.8	180 (1)	210 (1)
2.5	165	253
2.8	155	230
3.0	145	220
3.1	140	210
3.3	135	200

1. *Measured value.*

6.4 Input and output capacitors

The LD59030 requires external capacitors to assure the regulator control loop stability.

Any good quality ceramic capacitor can be used but, the X5R and the X7R are suggested since they guarantee a very stable combination of capacitance and ESR over the whole temperature range.

Locating the input/output capacitors as close as possible to the relative pins is recommended.

The LD59030 requires an input capacitor with a minimum value of 1 µF. This capacitor must be located as close as possible to the input pin of the device and returned to a clean analog ground.

The control loop of the LD59030 is designed to work with an output ceramic capacitor.

This capacitor must meet the requirements of minimum capacitance and equivalent series resistance (ESR), as shown in Figure 15. Stability area vs. (C_{OUT}, ESR). To assure stability, the output capacitor must maintain its ESR and capacitance in the stable region, over the full operating temperature range.

In order to keep stability in all operating conditions (temperature, input voltage and load variations), a minimum output capacitor of 0.47 µF is recommended.

The suggested combination of 1 µF input and output capacitors offers a good compromise among the stability of the regulator, optimum transient response and total PCB area occupation.

7 Typical characteristics

(C_{IN} = C_{OUT} = 1 µF, V_{EN} to V_{IN}, T_J = 25°C unless otherwise specified)

Figure 4. Output voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 1 mA)

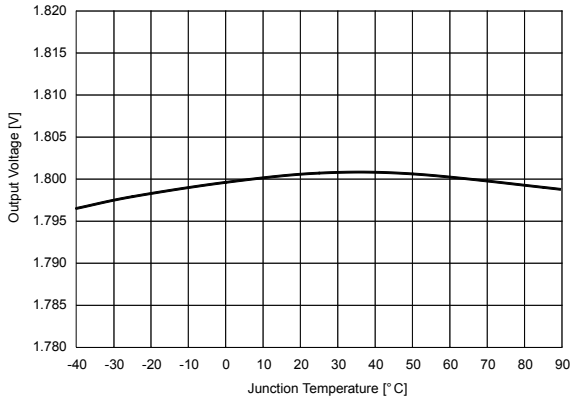


Figure 5. Output voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 300 mA)

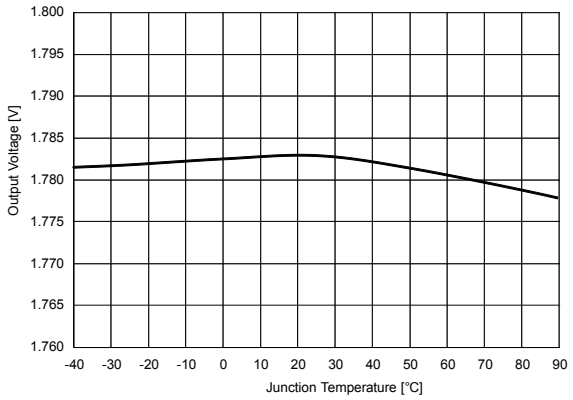


Figure 6. Line regulation vs. temperature (V_{IN} = 2.8 V to 5.5 V; V_{OUT} = 1.8 V; I_{OUT} = 10 mA)

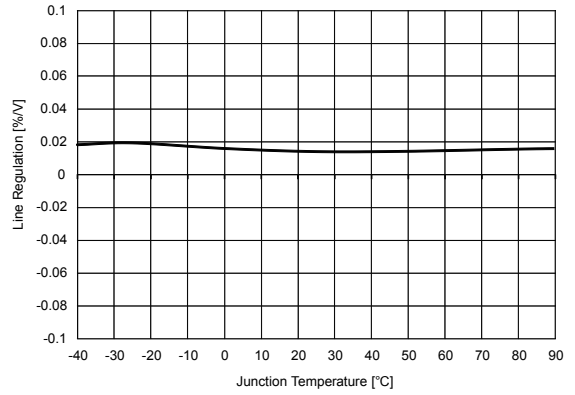


Figure 7. Load regulation vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 0 to 300 mA)

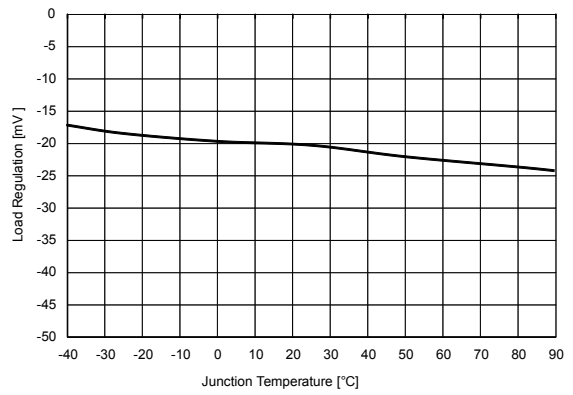


Figure 8. Quiescent current vs. temperature (I_{OUT} = 0 mA)

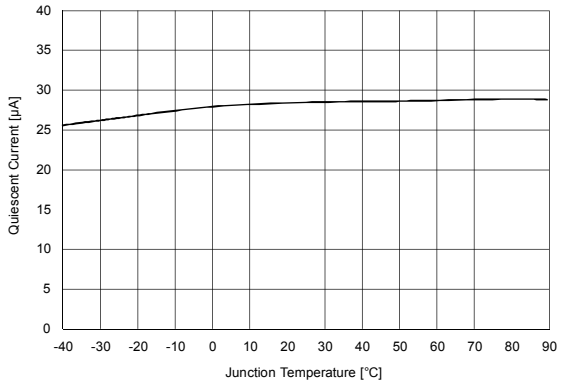


Figure 9. Quiescent current vs. temperature (I_{OUT} = 300 mA)

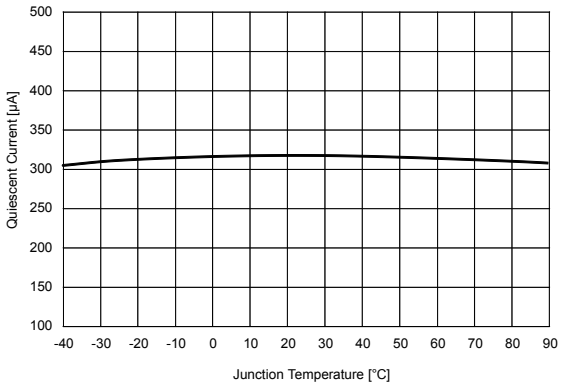


Figure 10. Shutdown current vs. temperature

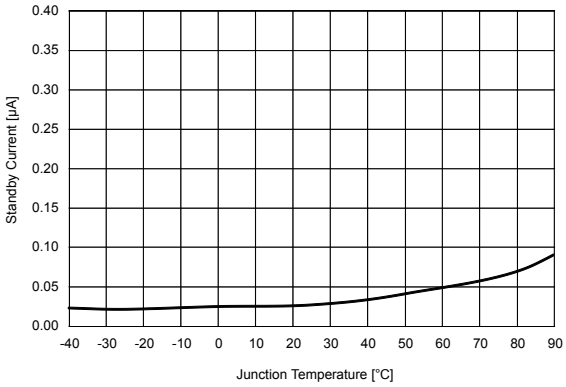


Figure 11. Dropout voltage vs. load current

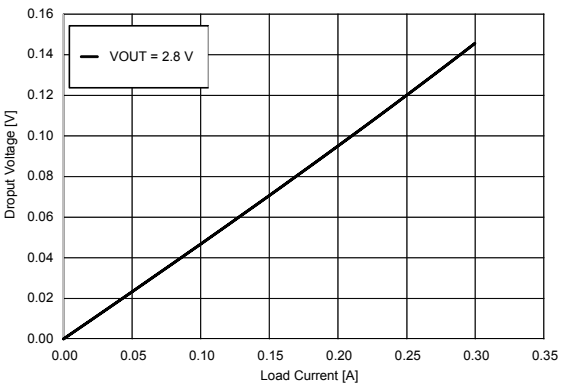


Figure 12. Quiescent current vs. output current (V_{IN} = 2.8 V; V_{OUT} = 1.8 V)

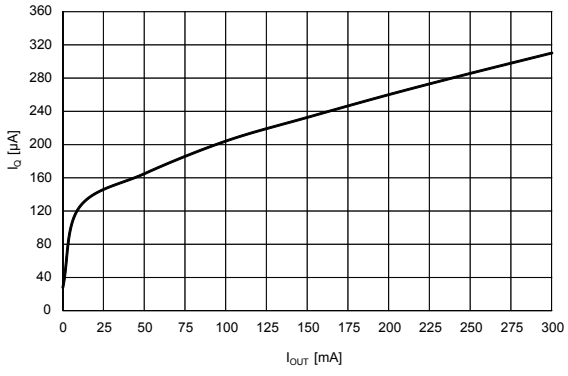


Figure 13. Dropout voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 300 mA)

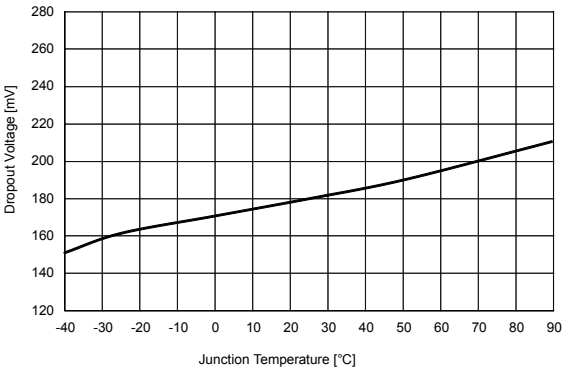


Figure 14. Supply voltage rejection vs. frequency

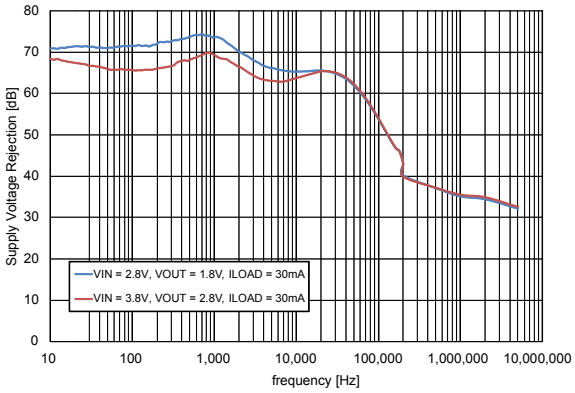


Figure 15. Stability area vs. (C_{OUT}, ESR)

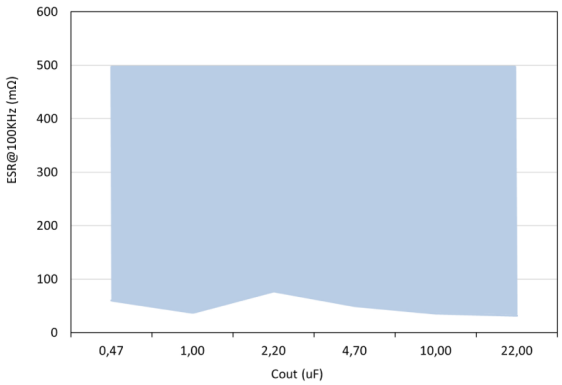


Figure 16. Output noise spectral density (V_{OUT} = 1.8 V)

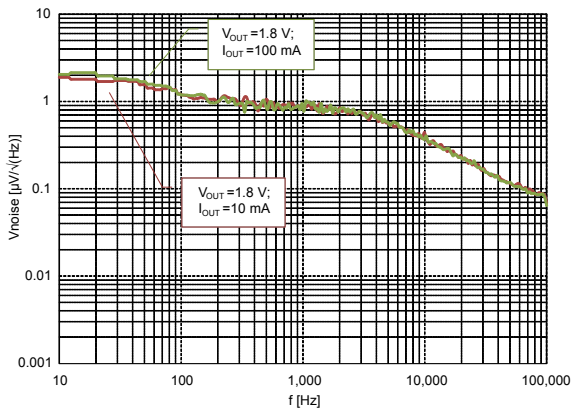


Figure 17. Output noise spectral density (V_{OUT} = 2.8 V)

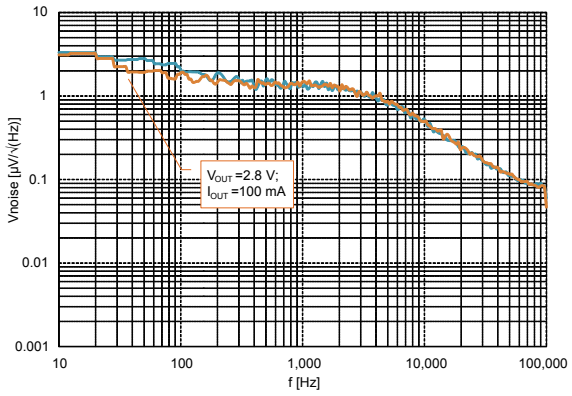


Figure 18. Turn-on Time (V_{OUT} = 1.8 V; I_{OUT} = 0 A, V_{IN} = 2.8 V, $t_r = t_f$ = 1 µs)

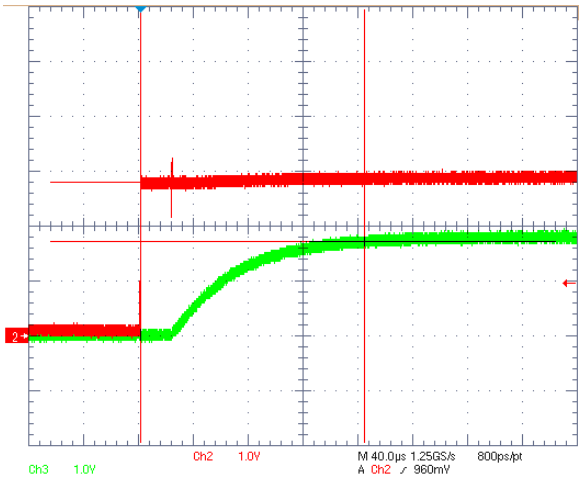


Figure 19. Line transient (V_{OUT} = 1.8 V; I_{OUT} = 10 mA, $t_r = t_f$ = 1 µs)

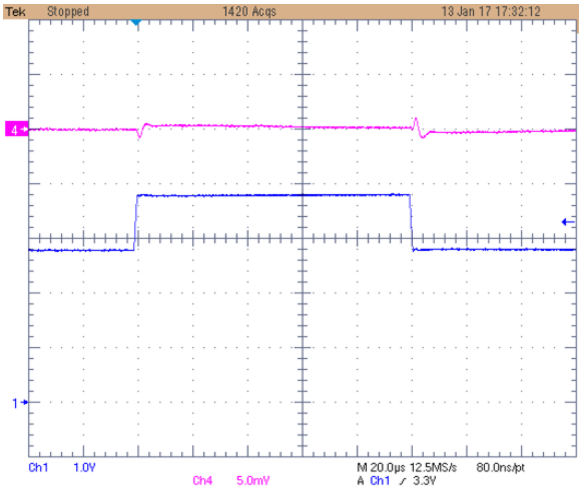


Figure 20. Output voltage vs. input voltage

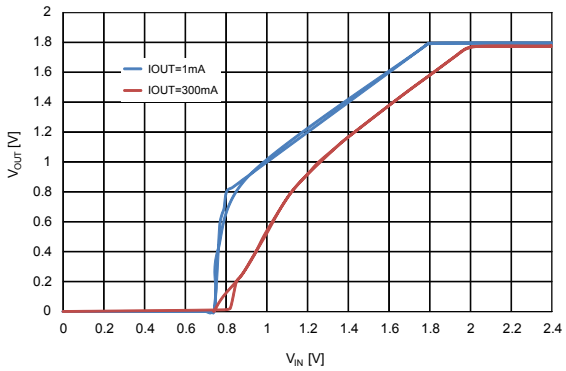
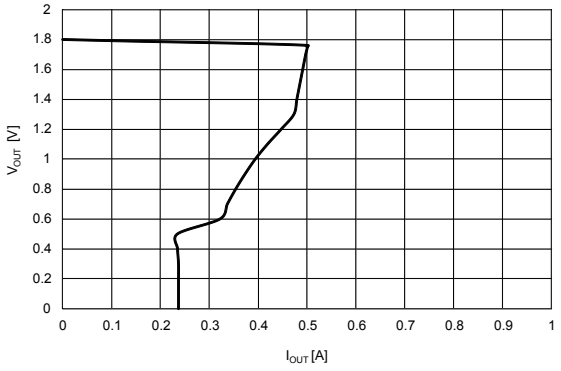


Figure 21. Output voltage vs. output current



8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

8.1 DFN4 1x1 package info

Figure 22. **DFN4 1x1 package outline**

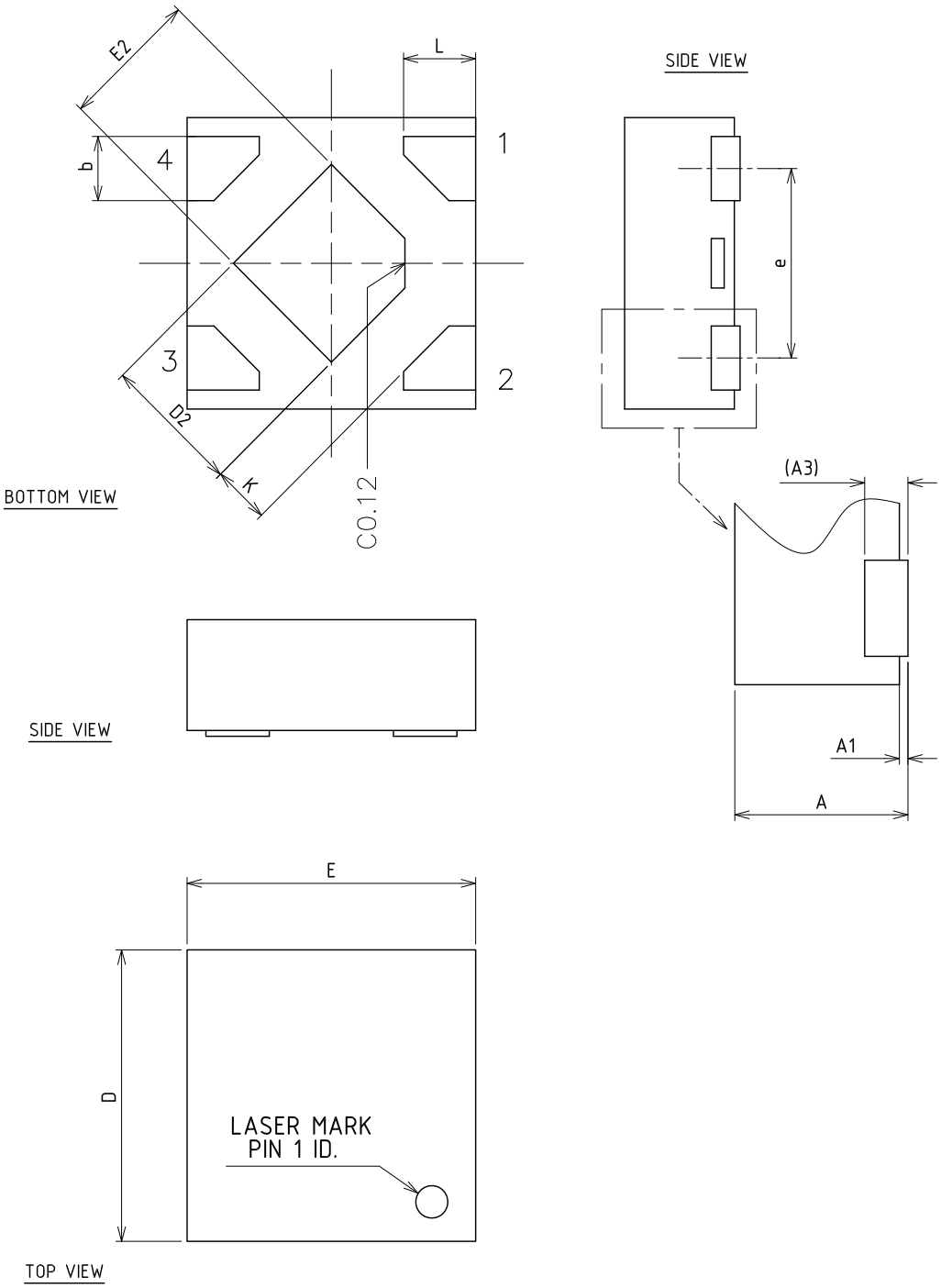


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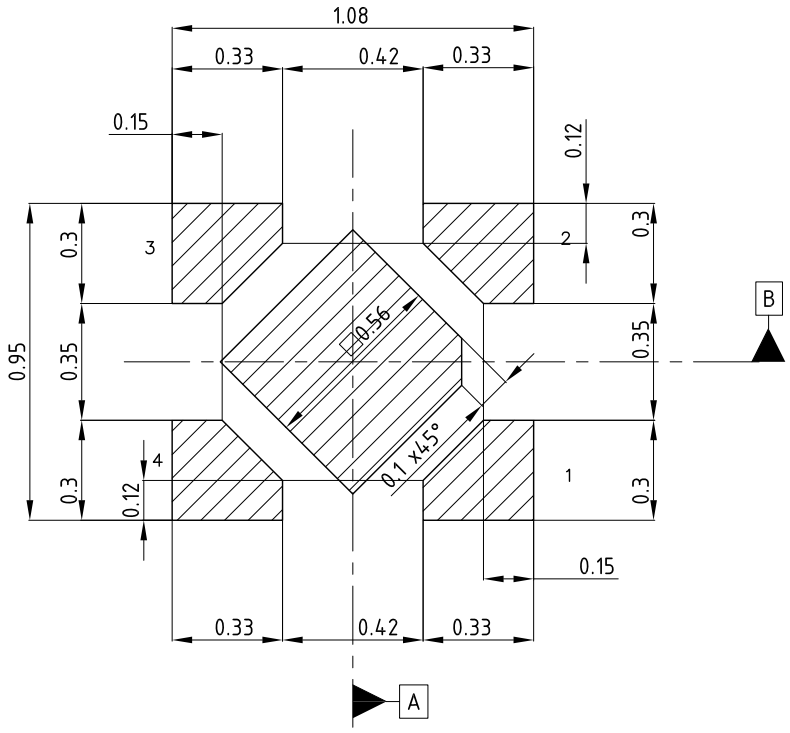
Table 7. **DFN4 1x1 mechanical data**

Dim.	mm.		
	Min.	Typ.	Max.
A	0.34	0.37	0.40
A1	0	0.02	0.05
A3		0.10	
b	0.17	0.22	0.27
D	0.95	1.00	1.05
D2	0.43	0.48	0.53
E	0.95	1.00	1.05
E2	0.43	0.48	0.53
e		0.65	
L	0.20	0.25	0.30
K	0.15		

Figure 23. DFN4 1x1 recommended footprint



Notes:

1) This footprint is able to ensure insulation up to 10 Vrms (according to CEI IEC 664-1)

2) The device must be positioned within ⌖ 0.02 A B

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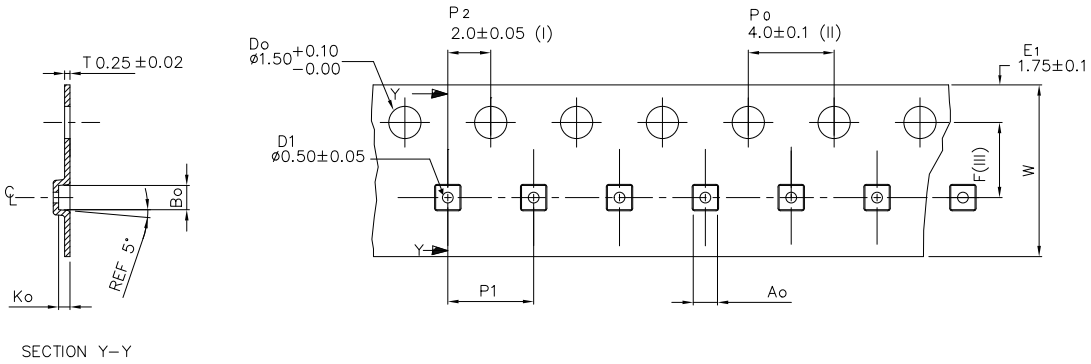
8.2 DFN4 1x1 packing information

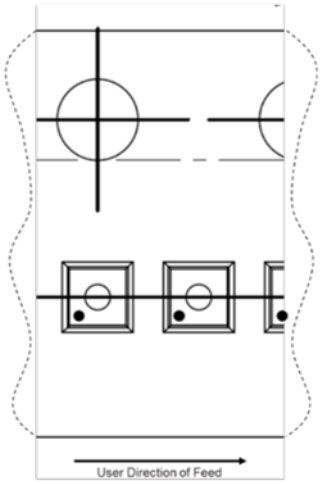
Figure 24. **Tape dimensions**



Ao	1.13 +/−0.05
Bo	1.13 +/−0.05
Ko	0.53 +/−0.05
F	3.50 +/−0.05
P1	4.00 +/−0.10
W	8.00 +0.3/−0.1

(I) Measured from centreline of sprocket hole to centreline of pocket.
(II) Cumulative tolerance of 10 sprocket holes is ± 0.20 .
(III) Measured from centreline of sprocket hole to centreline of pocket.
(IV) Other material available.
(V) Typical SR of form tape Max. 10^9 OHM/SR

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.



9 Ordering information

Table 8. **Order code**

Order code	Output voltage (V)	Auto-discharge	Marking
LD59030DTPU105R	1.05	Yes	JQ
LD59030TPU105R		No	KQ
LD59030DTPU12R	1.2	Yes	J5
LD59030TPU12R		No	K5
LD59030DTPU18R	1.8	Yes	J7
LD59030TPU18R		No	K7
LD59030DTPU25R	2.5	Yes	JA
LD59030TPU25R		No	KA
LD59030DTPU28R	2.8	Yes	JC
LD59030TPU28R		No	KC
LD59030DTPU30R	3.0	Yes	JF
LD59030TPU30R		No	KF
LD59030DTPU33R	3.3	Yes	JJ
LD59030TPU33R		No	KJ

Revision history

Table 9. **Document revision history**

Date	Revision	Changes
28-Aug-2017	1	Initial release.
03-Nov-2017	2	Datasheet promoted from preliminary data to datasheet. Update Figure 15: "Stability area vs. (COUT, ESR)".
01-Jun-2018	3	Updated: Figure 24. Tape dimensions.
31-Jul-2018	4	Updated: output voltage in Table 6. Dropout voltage at I_{OUT} = 300 mA.

Contents

1 Diagram 2
2 Pin configuration 3
3 Typical application 4
4 Maximum ratings 5
5 Electrical characteristics 6
6 Application information 8
6.1 Soft-start function 8
6.2 Output discharge function 8
6.3 Dropout voltage 8
6.4 Input and output capacitors 8
7 Typical characteristics 9
8 Package information 13
8.1 DFN4 1x1 package information 13
8.2 DFN4 1x1 packing information 16
9 Ordering information 18
Revision history 19

List of tables

Table 1. Pin description . . . 3
Table 2. Absolute maximum ratings . . . 5
Table 3. Thermal data . . . 5
Table 4. ESD Performance . . . 5
Table 5. Electrical characteristics . . . 6
Table 6. Dropout voltage at I_{OUT} = 300 mA . . . 8
Table 7. DFN4 1x1 mechanical data . . . 15
Table 8. Order code . . . 18
Table 9. Document revision history . . . 19

List of figures

Figure 1. Block diagram . . . 2
Figure 2. Pin connection (top view) . . . 3
Figure 3. Typical application circuit . . . 4
Figure 4. Output voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 1 mA) . . . 9
Figure 5. Output voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 300 mA) . . . 9
Figure 6. Line regulation vs. temperature (V_{IN} = 2.8 V to 5.5 V; V_{OUT} = 1.8 V; I_{OUT} = 10 mA) . . . 9
Figure 7. Load regulation vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 0 to 300 mA) . . . 9
Figure 8. Quiescent current vs. temperature (I_{OUT} = 0 mA) . . . 10
Figure 9. Quiescent current vs. temperature (I_{OUT} = 300 mA) . . . 10
Figure 10. Shutdown current vs. temperature . . . 10
Figure 11. Dropout voltage vs. load current . . . 10
Figure 12. Quiescent current vs. output current (V_{IN} = 2.8 V; V_{OUT} = 1.8 V) . . . 10
Figure 13. Dropout voltage vs. temperature (V_{OUT} = 1.8 V; I_{OUT} = 300 mA) . . . 10
Figure 14. Supply voltage rejection vs. frequency . . . 11
Figure 15. Stability area vs. (C_{OUT}, ESR) . . . 11
Figure 16. Output noise spectral density (V_{OUT} = 1.8 V) . . . 11
Figure 17. Output noise spectral density (V_{OUT} = 2.8 V) . . . 11
Figure 18. Turn-on Time (V_{OUT} = 1.8 V; I_{OUT} = 0 A, V_{IN} = 2.8 V, t_r = t_f = 1 µs) . . . 12
Figure 19. Line transient (V_{OUT} = 1.8 V; I_{OUT} = 10 mA, t_r = t_f = 1 µs) . . . 12
Figure 20. Output voltage vs. input voltage . . . 12
Figure 21. Output voltage vs. output current . . . 12
Figure 22. DFN4 1x1 package outline . . . 14
Figure 23. DFN4 1x1 recommended footprint . . . 16
Figure 24. Tape dimensions . . . 17

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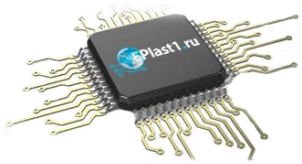
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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